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# 2SC4208, 2SC4208A

## Silicon NPN epitaxial planar type

For low-frequency output amplification and driver amplification  
Complementary to 2SA1619 and 2SA1619A

### ■ Features

- Low collector-emitter saturation voltage  $V_{CE(sat)}$
- Output of 1 W is obtained with a complementary pair with 2SA1619 and 2SA1619A
- Allowing supply with the radial taping

### ■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	2SC4208	$V_{CBO}$	30	V
	2SC4208A		60	
Collector-emitter voltage (Base open)	2SC4208	$V_{CEO}$	25	V
	2SC4208A		50	
Emitter-base voltage (Collector open)	$V_{EBO}$	7	V	
Collector current	$I_C$	500	mA	
Peak collector current	$I_{CP}$	1	A	
Collector power dissipation	$P_C$	1	W	
Junction temperature	$T_j$	150	$^\circ\text{C}$	
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$	

### ■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

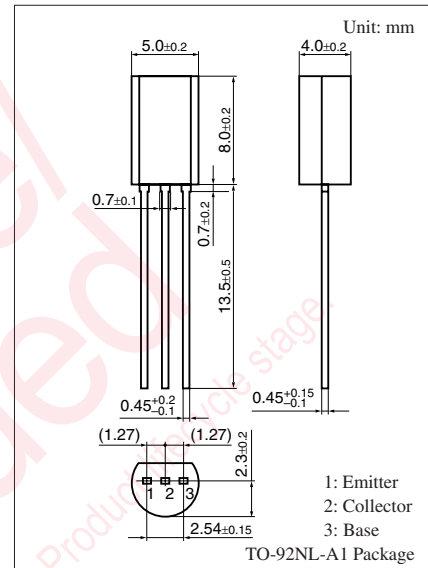
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	2SC4208	$I_C = 10 \mu\text{A}, I_E = 0$	30			V
	2SC4208A		60			
Collector-emitter voltage (Base open)	2SC4208	$I_C = 10 \text{ mA}, I_B = 0$	25			V
	2SC4208A		50			
Emitter-base voltage (Collector open)	$V_{EBO}$	$I_E = 10 \mu\text{A}, I_C = 0$	7			V
Forward current transfer ratio *1	$h_{FE1}$ *2	$V_{CE} = 10 \text{ V}, I_C = 150 \text{ mA}$	85		340	—
	$h_{FE2}$	$V_{CE} = 10 \text{ V}, I_C = 500 \text{ mA}$	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$		0.35	0.60	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$		1.1	1.5	V
Transition frequency	$f_T$	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		150		MHz
Collector output capacitance (Common base, input open circuited)	$C_{ob}$	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		6	15	pF

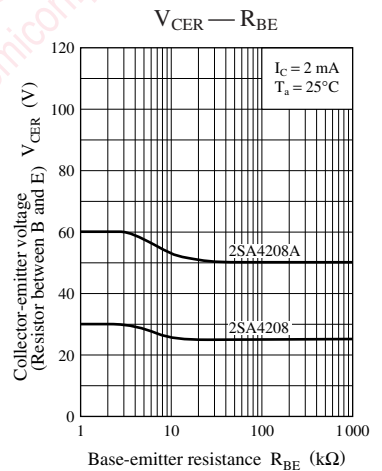
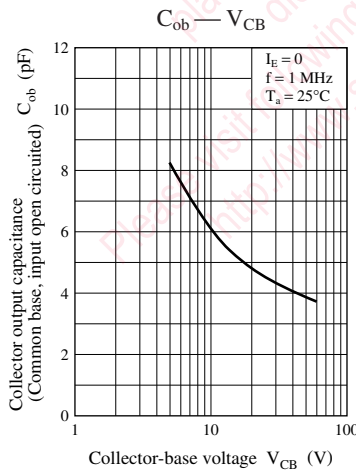
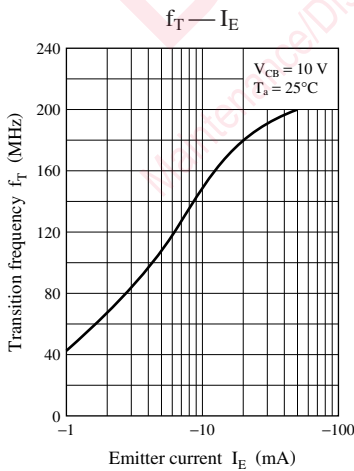
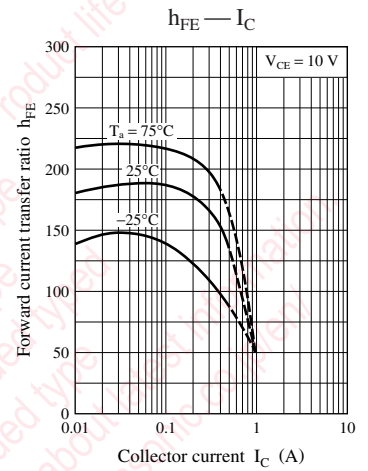
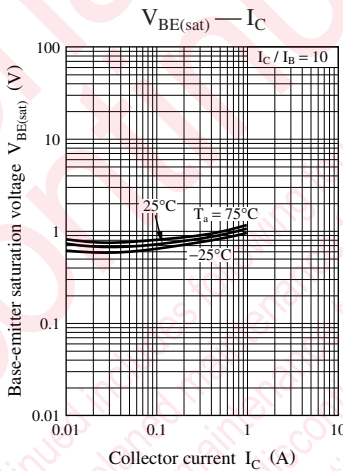
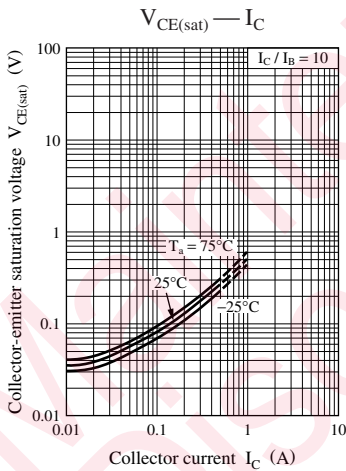
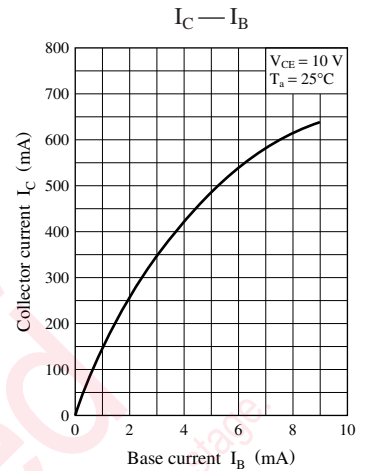
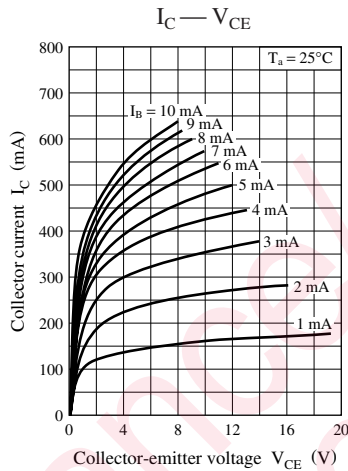
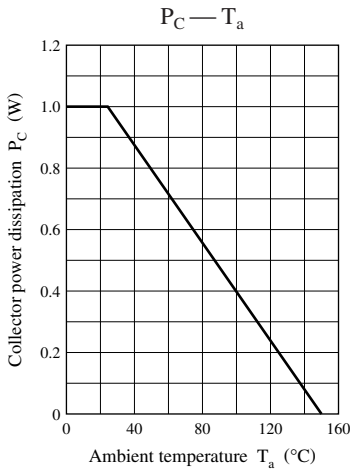
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

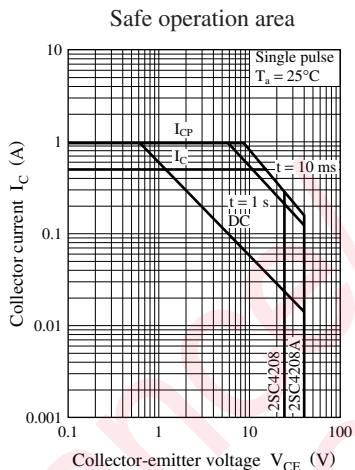
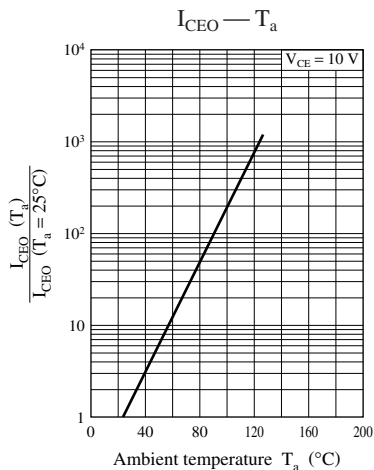
2. \*1: Pulse measurement

\*2: Rank classification

Rank	Q	R	S
$h_{FE1}$	85 to 170	120 to 240	170 to 340







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maintenance type  
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